

FE4M

SINTERED GLASS JUNCTION ULTRAFAST AVALANCHE RECTIFIER

VOLTAGE: 1000V

CURRENT: 3.0A

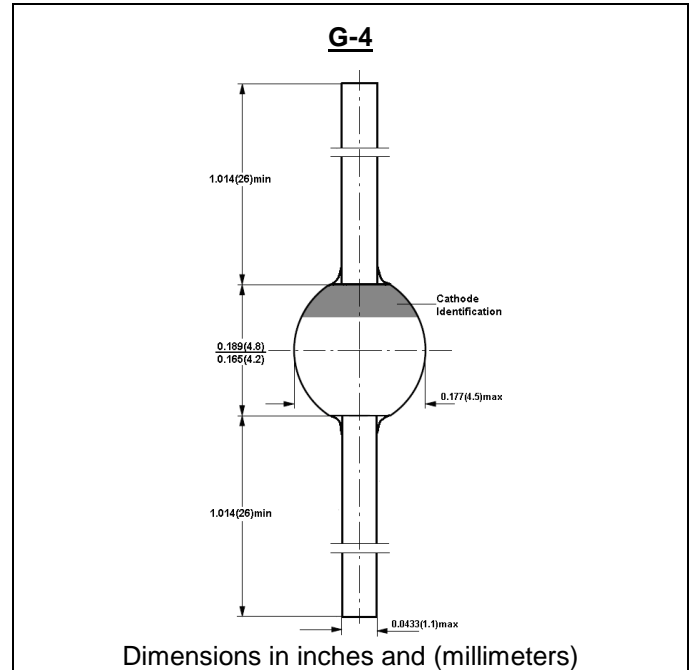


FEATURE

Glass passivated
Hermetically sealed package
Low reverse current
Soft recovery characteristics

MECHANICAL DATA

Case: G-4 sintered glass case
Terminal: Plated axial leads solderable per
MIL-STD 202E, method 208C
Polarity: color band denotes cathode end
Mounting position: any



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(single-phase, half-wave, 60HZ, resistive or inductive load rating at 25°C, unless otherwise stated)

| | SYMBOL | FE4M | units |
|---|----------------|-------------|---------------------------|
| Maximum Recurrent Peak Reverse Voltage | V_{RRM} | 1000 | V |
| Maximum RMS Voltage | V_{RMS} | 700 | V |
| Maximum DC blocking Voltage | V_{DC} | 1000 | V |
| Maximum Average Forward Rectified Current 3/8"lead length at $T_a=55^\circ\text{C}$ | I_{FAV} | 3.0 | A |
| Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load | I_{FSM} | 100 | A |
| Maximum Forward Voltage at rated Forward Current and 25°C | V_F | 1.75 | V |
| Maximum DC Reverse Current at rated DC Blocking Voltage | I_R | 5.0 100 | μA |
| Maximum Reverse Recovery Time (Note 1) | T_{rr} | 50 | nS |
| Typical Junction Capacitance (Note 2) | C_j | 100.0 | pF |
| Typical Thermal Resistance (Note 3) | $R_{th(ja)}$ | 20.0 | $^\circ\text{C}/\text{W}$ |
| Storage and Operating Junction Temperature | T_{stg}, T_j | -65 to +175 | $^\circ\text{C}$ |

Note:

1. Reverse Recovery Condition $I_f = 0.5\text{A}$, $I_r = 1.0\text{A}$, $I_{rr} = 0.25\text{A}$
2. Measured at 1.0 MHz and applied reverse voltage of 4.0Vdc
3. Thermal Resistance from Junction to Ambient at 3/8"lead length, P.C. Board Mounted

RATINGS AND CHARACTERISTIC CURVES FE4M

